



### Features

- 1.2-KVolt Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Positive Temperature Coefficient on  $V_F$

### Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

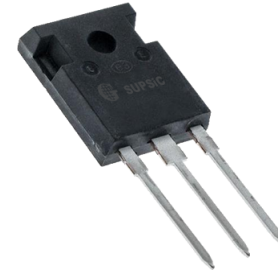
### Applications

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters

$$V_{RRM} = 1200 \text{ V}$$

$$I_F (T_c=135^\circ\text{C}) = 24 \text{ A}^{**}$$

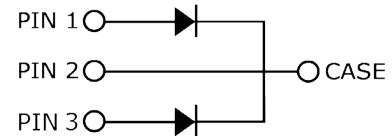
$$Q_c = 74 \text{ nC}^{**}$$



TO-247-3

### Package

Part Number	Package	Marking
GC4D15120D	TO-247-3	GC4D15120



### Maximum Ratings ( $T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value		Test Conditions	Note
$V_{RRM}$	Repetitive Peak Reverse Voltage	1200	V		
$V_{RSM}$	Surge Peak Reverse Voltage	1300	V		
$V_{DC}$	DC Blocking Voltage	1200	V		
$I_F$	Continuous Forward Current (Per Leg/Device)	24.5/49 12/24 7.5/15	A	$T_c=25^\circ\text{C}$ $T_c=135^\circ\text{C}$ $T_c=157^\circ\text{C}$	Fig. 3
$I_{FRM}$	Repetitive Peak Forward Surge Current	38* 25*	A	$T_c=25^\circ\text{C}, t_p=10 \text{ ms}$ , Half Sine Pulse $T_c=110^\circ\text{C}, t_p=10 \text{ ms}$ , Half Sine Pulse	
$I_{FSM}$	Non-Repetitive Peak Forward Surge Current	66* 49.5*	A	$T_c=25^\circ\text{C}, t_p=10 \text{ ms}$ , Half Sine Pulse $T_c=110^\circ\text{C}, t_p=10 \text{ ms}$ , Half Sine Pulse	Fig. 8
$I_{FMax}$	Non-Repetitive Peak Forward Current	600* 480*	A	$T_c=25^\circ\text{C}, t_p=10 \mu\text{s}$ , Pulse $T_c=110^\circ\text{C}, t_p=10 \mu\text{s}$ , Pulse	Fig. 8
$P_{tot}$	Power Dissipation(Per Leg/Device)	135/270 58.5/117	W	$T_c=25^\circ\text{C}$ $T_c=110^\circ\text{C}$	Fig. 4
dV/dt	Diode dV/dt ruggedness	200	V/ns	$V_R=0-960\text{V}$	
$\int i^2 dt$	$i^2t$ value	20.5* 12.25*	A <sup>2</sup> s	$T_c=25^\circ\text{C}, t_p=10 \text{ ms}$ $T_c=110^\circ\text{C}, t_p=10 \text{ ms}$	
$T_J, T_{stg}$	Operating Junction and Storage Temperature	-55 to +175	$^\circ\text{C}$		
	TO-247 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	

### Electrical Characteristics (Per Leg)

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
$V_F$	Forward Voltage	1.5 2.2	1.8 3	V	$I_F = 8\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 8\text{ A}$ $T_J = 175^\circ\text{C}$	Fig. 1
$I_R$	Reverse Current	35 100	250 350	$\mu\text{A}$	$V_R = 1200\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 1200\text{ V}$ $T_J = 175^\circ\text{C}$	Fig. 2
$Q_C$	Total Capacitive Charge	37		nC	$V_R = 800\text{ V}$ , $I_F = 8\text{ A}$ $di/dt = 200\text{ A}/\mu\text{s}$ $T_J = 25^\circ\text{C}$	Fig. 5
C	Total Capacitance	560 37 27		pF	$V_R = 0\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$ $V_R = 400\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$ $V_R = 800\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$	Fig. 6
$E_C$	Capacitance Stored Energy	10.5		$\mu\text{J}$	$V_R = 800\text{ V}$	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

### Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	1.11* 0.56**		$^\circ\text{C}/\text{W}$	Fig. 9

\* Per Leg, \*\* Per Device

### Typical Performance

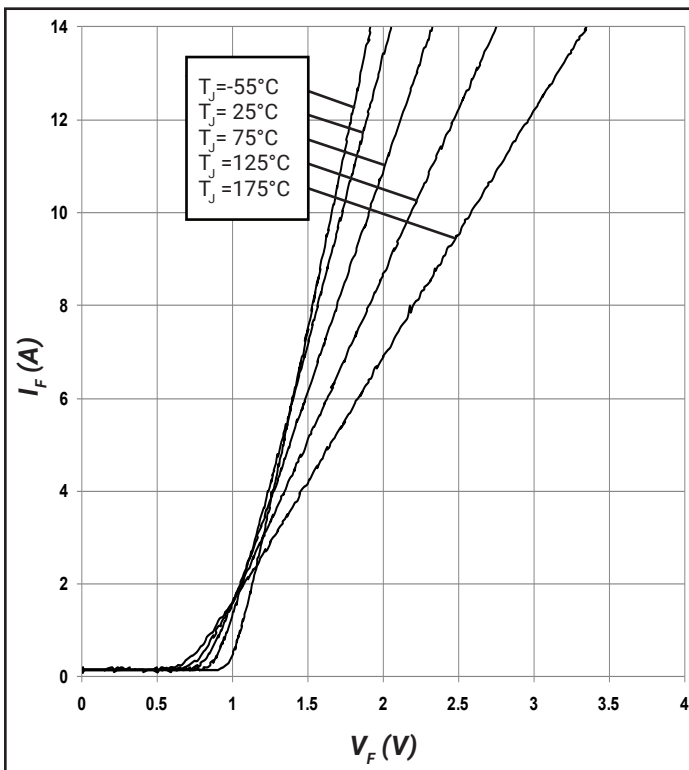


Figure 1. Forward Characteristics

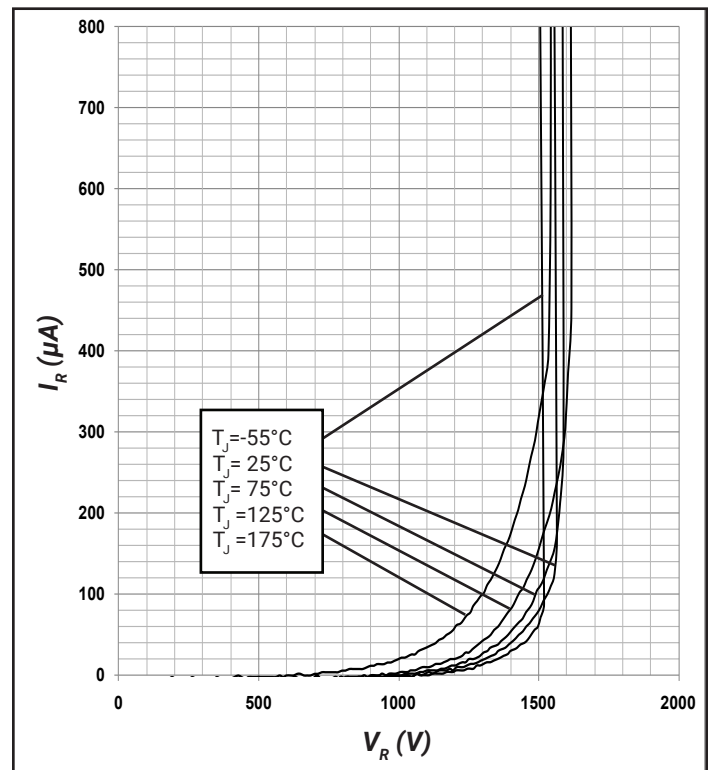


Figure 2. Reverse Characteristics

Typical Performance (Per Leg)

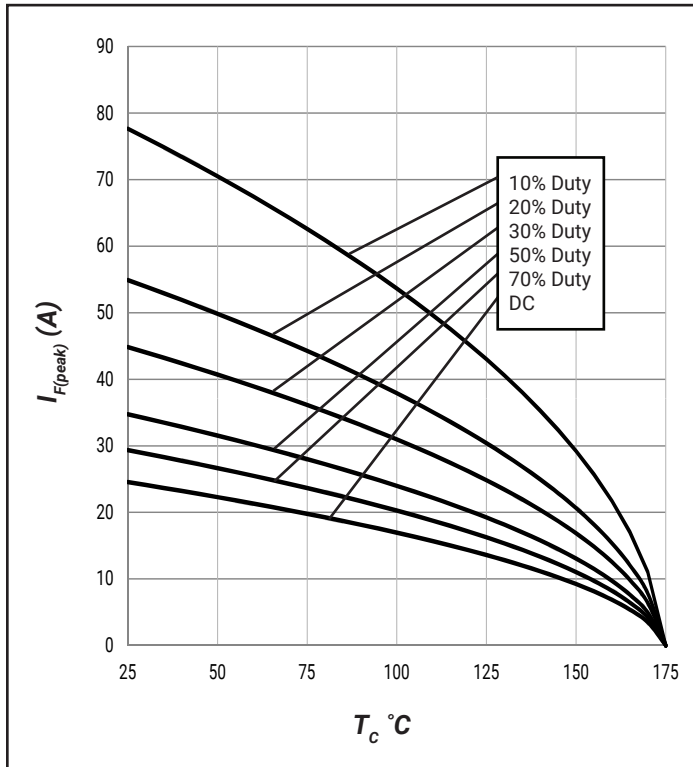


Figure 3. Current Derating

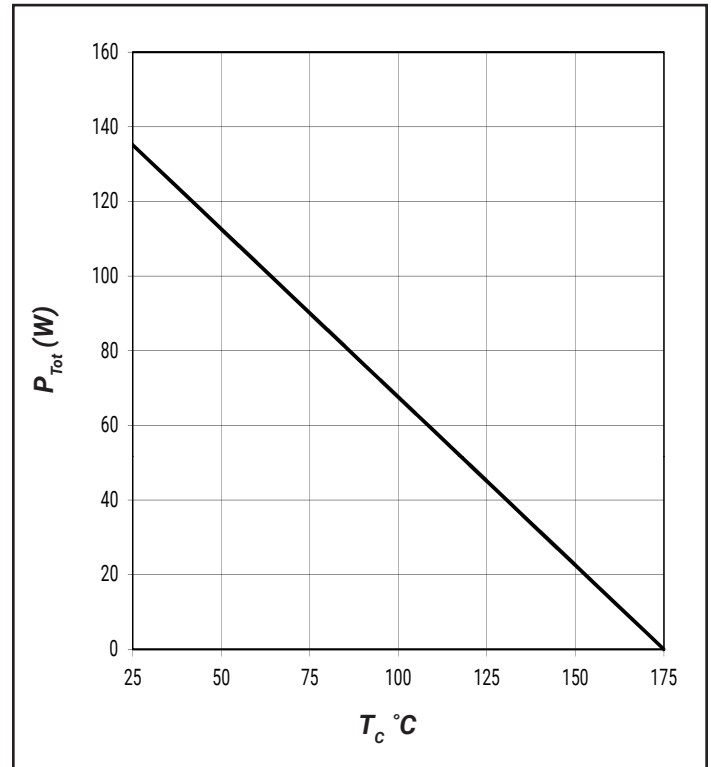


Figure 4. Power Derating

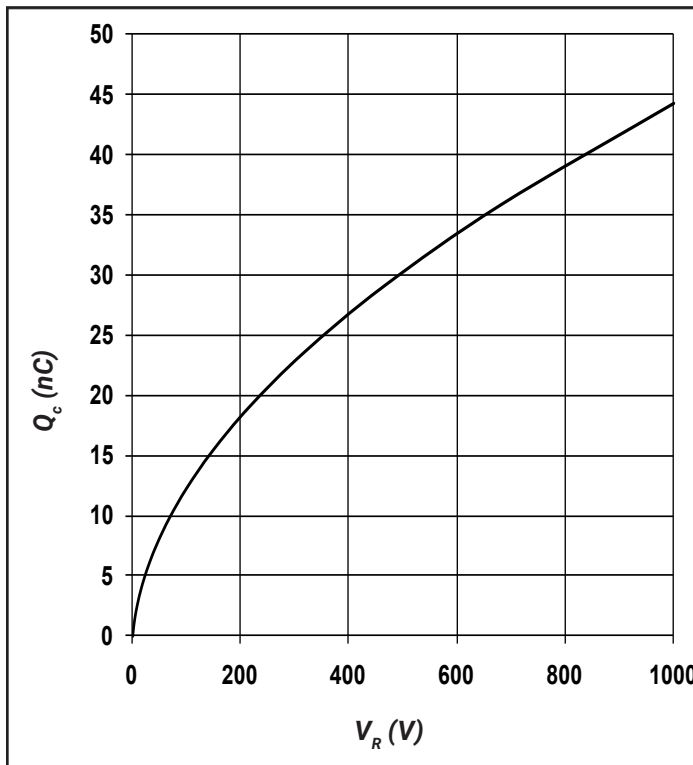


Figure 5. Recovery Charge vs. Reverse Voltage

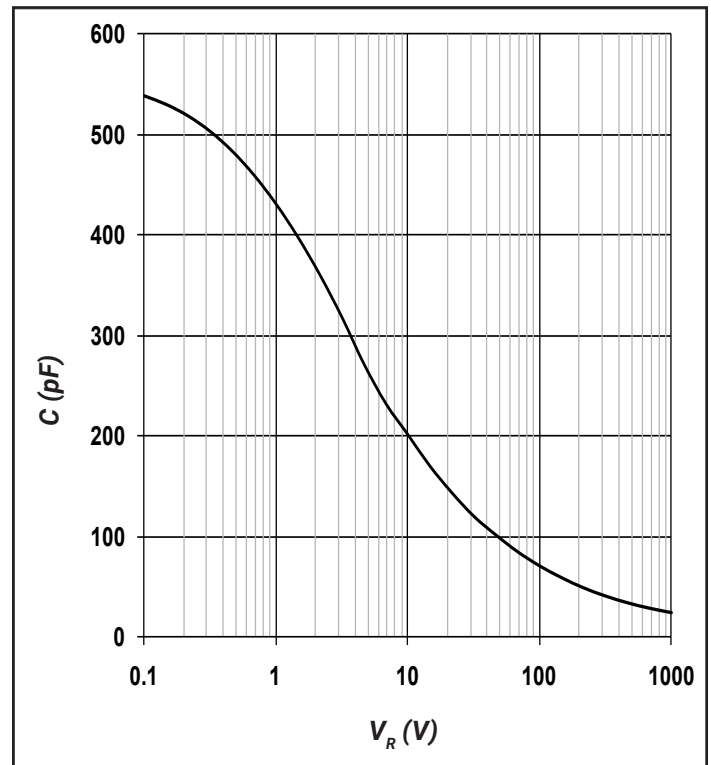


Figure 6. Capacitance vs. Reverse Voltage

Typical Performance

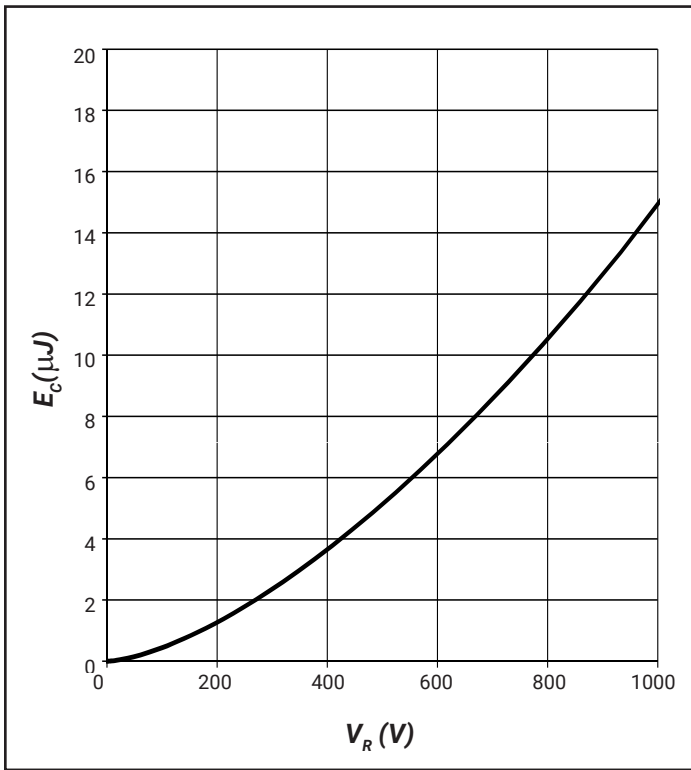


Figure 7. Typical Capacitance Stored Energy, per leg

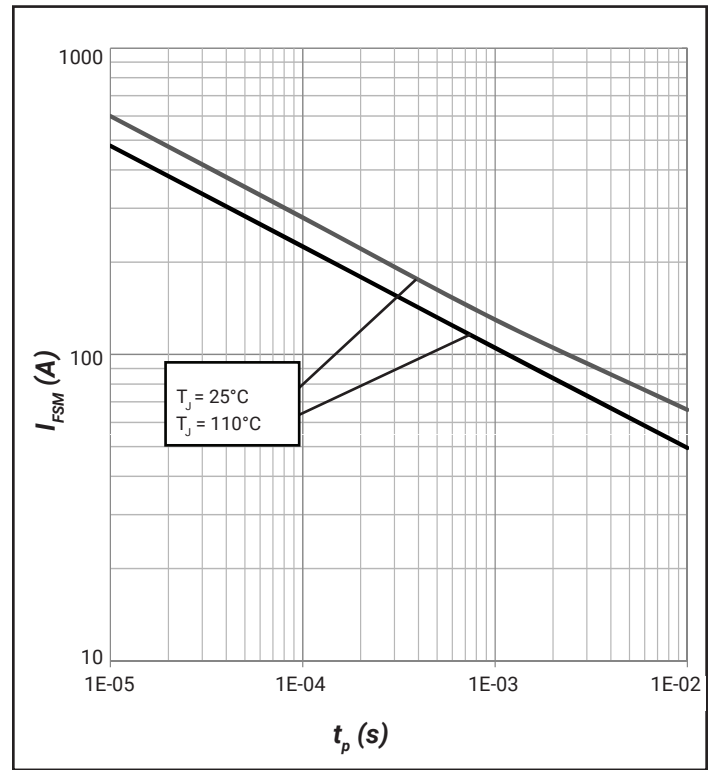


Figure 8. Non-repetitive Peak Forward Surge Current vs. Pulse Duration (sinusoidal waveform), per leg

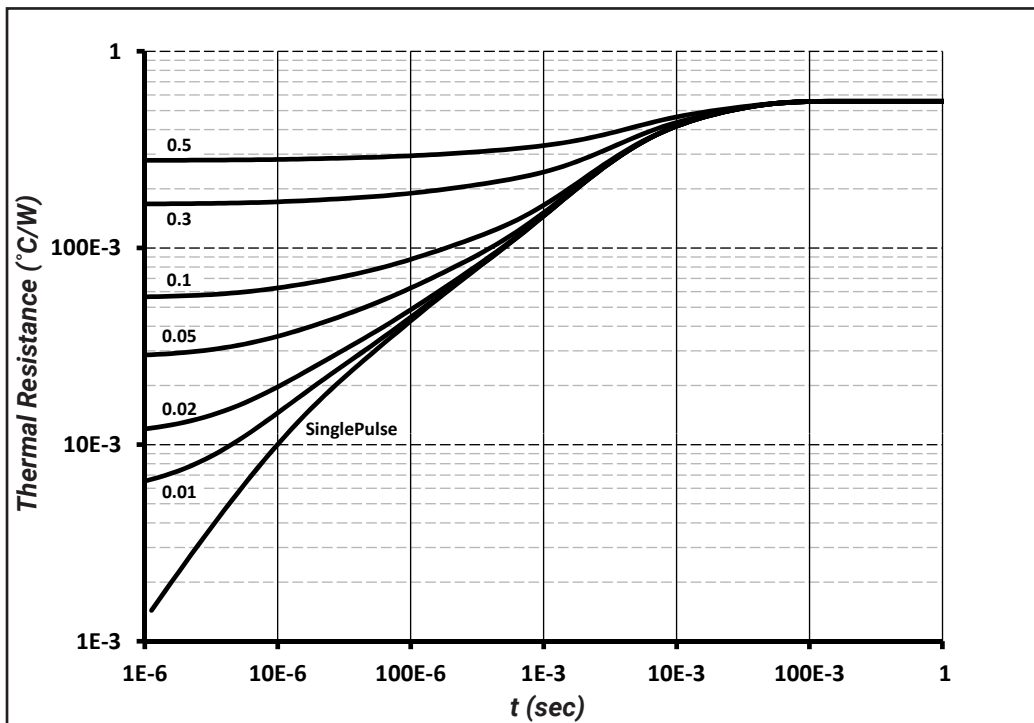
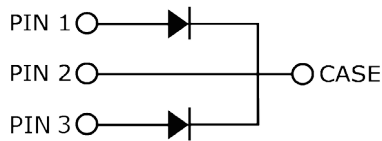
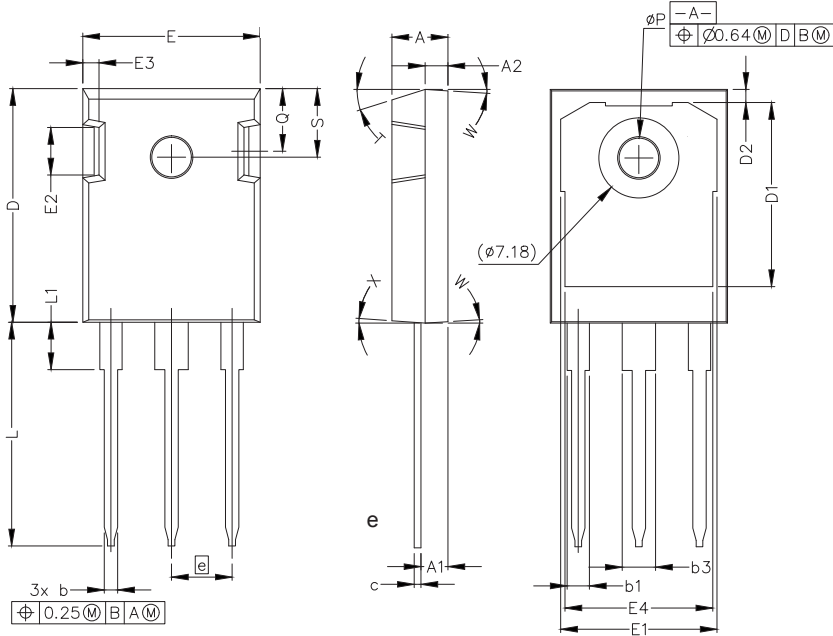


Figure 9. Device Transient Thermal Impedance

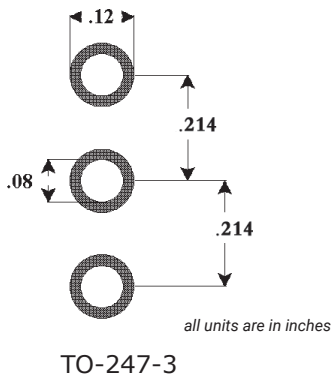
### Package Dimensions

Package TO-247-3



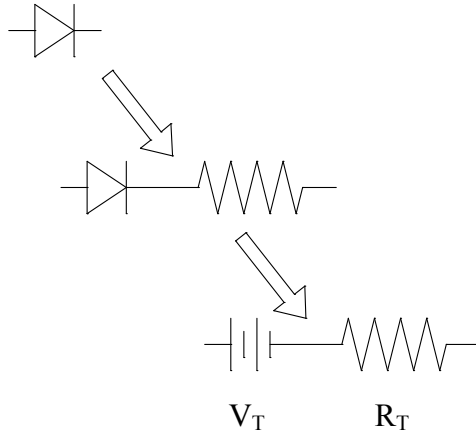
POS	Inches		Millimeters	
	Min	Max	Min	Max
A	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.042	.052	1.07	1.33
b1	.075	.095	1.91	2.41
b3	.113	.133	2.87	3.38
c	.022	.027	0.55	0.68
D	.819	.831	20.80	21.10
D1	.640	.695	16.25	17.65
D2	.037	.049	0.95	1.25
E	.620	.635	15.75	16.13
E1	.516	.557	13.10	14.15
E2	.145	.201	3.68	5.10
E3	.039	.075	1.00	1.90
E4	.487	.529	12.38	13.43
e	.214 BSC		5.44 BSC	
L	.780	.800	19.81	20.32
L1	.161	.173	4.10	4.40
N	3			
ØP	.138	.144	3.51	3.65
Q	.216	.236	5.49	6.00
S	.238	.248	6.04	6.30
T	17.5° REF			
W	3.5° REF			
X	4° REF			

### Recommended Solder Pad Layout



Part Number	Package
GC4D15120D	TO-247-3

Diode Model



$$V_{fT} = V_T + I_f * R_T$$

$$V_T = 0.96 + (T_J * -2.1 * 10^{-3})$$

$$R_T = 0.06 + (T_J * 8.0 * 10^{-4})$$

Note:  $T_J$  = Diode Junction Temperature In Degrees Celsius,  
valid from 25°C to 175°C